Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

## **Overall Length:**

Between 0.140 inches and 0.195 inches

# **Terminal Length:**

Between 0.900 inches and 1.300 inches

## **Overall Diameter:**

Between 0.135 inches and 0.185 inches

#### **Function For Which Designed:**

Transient suppressor

#### **Mounting Method:**

Terminal

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

14.25 breakdown voltage, instantaneous and 15.75 breakdown voltage, instantaneous

#### **Current Rating Per Characteristic:**

20.00 microamperes forward current, average peak and 75.00 milliamperes collector current, dc horsepower metric

## **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector major

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## **Terminal Type And Quantity:**

2 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/516 government specification

Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

# Fiig:

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